300mA, Low Dropout, Ultra-Low Io Linear Regulators

DESCRIPTION

The LTP3636 series of CMOS low dropout regulators are designed specifically for portable battery-powered applications which require ultra-low power consumption. The ultra-low quiescent current of only 0.8µA ensures features of long battery life, and the built-in dynamic transient boost improves the device transient response for wireless communication applications.

The LTP3636 series are available in SOT23-3L and SOT23-5L packages.

FEATURES

- 0.8 μA Ultra-Low Quiescent Current
- Output Voltage Range: 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.3V, and 3.6V
- Operating Input Voltage Range: 2.0V to 5.5V
- Low Dropout: 170mV Typically at 150mA Load and 1.8V Output
- High Output Voltage Accuracy: ±1.5%
- Stable with 1μF Ceramic Capacitors
- Over-Current Protection
- Thermal Shutdown Protection
- With Auto Discharge Function at Off State

APPLICATIONS

- Battery Powered Equipments
- Portable Communication Equipments
- Cameras, Image Sensors and Camcorders
- Label Information

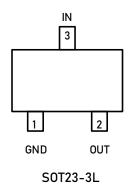
ORDER INFORMATION

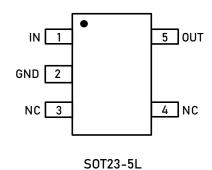
Model	Package	Ordering Number Notel	Packing Option
L TD2/2/	S0T23-3L	LTP3636-xxYT3	Tape and Reel, 3000
LTP3636	S0T23-5L	LTP3636-xxYT5	Tape and Reel, 3000

Note1: xx stands for output voltage, e.g. if xx = 18, the output voltage is 1.8V; if xx = 30, the output voltage is 3.0V.



PIN CONFIGURATION (Top View)





PIN DESCRIPTIONS

Pin		Symbol	Description	
S0T23-3	S0T23-5	Syllibot	Description	
3	1	IN	Power Supply Input Voltage	
1	2	GND	Ground.	
/	3	NC No Connection.		
/	4	NC	No Connection.	
2	5	OUT	Output Pin	

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value		Unit
Input Voltage	V_{IN}	6.5		V
Output Voltage	V _{out}	-0.3 to V _{IN} + 0.3		V
Operating Junction Temperature	T _J	150		°C
Storage Temperature	T _{STG}	−55 to 150		°C
Thermal Characteristics, Thermal	$R_{ heta JA}$	S0T23-3L	357	- °C /W
Resistance, Junction-to-Air		S0T23-5L	250	- C/W
Human Body Model	ECD	6000		V
ESD Capability	- ESD	2000		V
Current Maximum Rating	Latch up	n up 200		mA

NOTE:Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. LINEARIN recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

LINEARIN reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact LINEARIN sales office to get the latest datasheet.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	2.0 to 5.5	V
I _{out}	Output Current	0 to 300	mA
T _A	Operating Ambient Temperature	-40 to 85	°C
C _{IN}	Effective Input Ceramic Capacitor Value	0.47 to 4.7	μF
C _{OUT}	Effective Output Ceramic Capacitor Value	0.47 to 4.7	μF

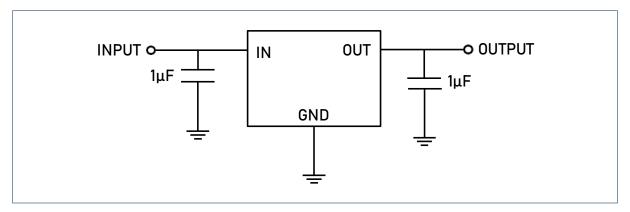
ELECTRICAL CHARACTERISTICS

 V_{IN} = 2.5 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, T_A = +25 °C, unless otherwise noted.

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
V _{IN}	Operating Input	•		2.0		5.5	٧
V _{OUT} Output Voltage	• • • • • • • • • • • • • • • • • • • •	T _A = +25 °C		−1.5		+1.5	_ 0/
	Output Voltage	-40 °C ≤ T _A ≤ 8	5 °C	-2.5		+2.5	– %
Iq	Quiescent Current	I _{out} = 0 mA			0.8	1.1	μΑ
Line _{Reg}	Line Regulation	$2.5 \text{ V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{ V}, \text{I}_{\text{OUT}} = 1 \text{ mA}$			0.1	0.2	%/V
Load _{Reg}	Load Regulation	$1 \text{ mA} \le I_{\text{OUT}} \le 150 \text{ mA}, V_{\text{IN}} = 2.5 \text{ V}$			20		mV
V _{DROP}	Dropout Voltage	I _{out} = 150 mA			170		mV
I _{_LMT}	Current Limit				300	550	mA
I _{SHORT}	Short Circuit Current	V _{OUT} = 0 V			90		mA
2022			f = 1 kHz		-55		_
PSRR	Power supply Rejection Ratio	I _{OUT} = 100 mA	f = 10 kHz		-52		dB
e _N	Output Noise Voltage	V_{IN} = 2.5 V, I_{OUT} = 1 mA, f = 10 Hz to 100 kHz, C_{OUT} = 1 μ F			100		μVrms



APPLICATION CIRCUITS



Applications Information

General

The LTP3636 is a high performance 300mA Linear Regulator with Ultra Low I_Q . This device delivers low Noise and high Power Supply Rejection Ratio with excellent dynamic performance due to employing the Dynamic Quiescent Current adjustment which assure ultra low I_Q consumption at noload state. These parameters make the LTP3636 device very suitable for various battery powered applications.

Input Decoupling (CIN)

It is recommended to connect at least a 1 μ F Ceramic X5R or X7R capacitor between IN and GND pins of the device. This capacitor will provide a low impedance path for any unwanted AC signals or Noise superimposed onto constant Input Voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes.

Higher capacitance and lower ESR Capacitors will improve the overall line transient response.

Output Decoupling (Cout)

The LTP3636 does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended. There is recommended connect the output capacitor as close as possible to the output pin of the regulator.

Current Limit Protection

When output current at the OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to approximately 550mA to prevent over-current and to protect the regulator from damage due to overheating.

Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown point (TSD =160°C typically) the device goes to disabled state and the output voltage is not delivered until the die temperature decreases to 150°C. The Thermal Shutdown feature provides a protection from a catastrophic device failure at accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.



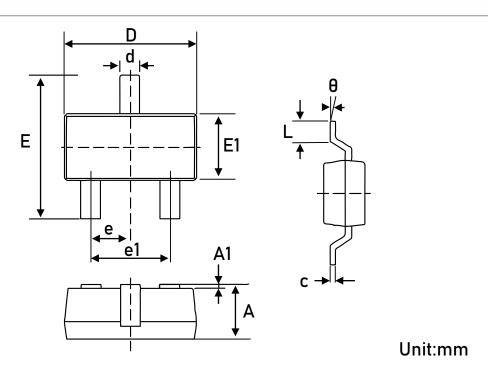
Power Dissipation and Heat sinking

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material and the ambient temperature affect the rate of junction temperature rise for the part. The maximum power dissipation the LTP3636 device can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_{A}\right]}{P_{\theta JA}}$$
 (eq.1)

PACKAGE OUTLINE

S0T23-3L

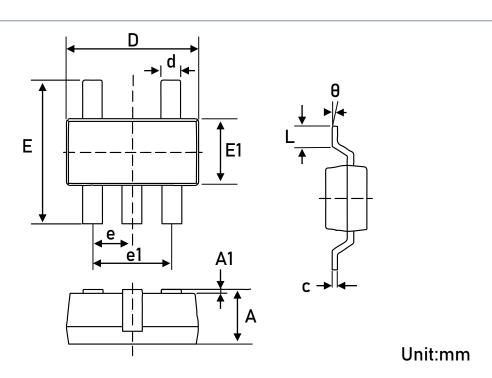


Symbol	Dimensions In Millimeters		
	MIN	MAX	
A	1.050	1.250	
A1	0.000	0.100	
b	0.300	0.400	
С	0.100	0.200	
D	2.820	3.020	
E	2.600	3.000	
E1	1.500	1.700	
е	0.950BSC		
e1	1.800	2.000	
L	0.300	0.600	
θ	0°	8°	



PACKAGE OUTLINE

S0T23-5L



•	Dimensions In Millimeters		
Symbol	MIN	MAX	
Α	1.050	1.250	
A1	0.000	0.100	
b	0.350	0.500	
С	0.080	0.200	
D	2.820	3.020	
E	2.600	3.000	
E1	1.600	1.700	
е	0.950BSC		
e1	1.800	2.000	
L	0.300	0.600	
θ	0 °	8°	

